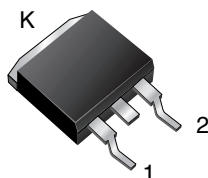
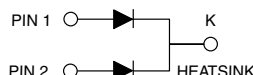


## Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

### D<sup>2</sup>PAK (TO-263AB)


**MBRB25HxxCT**


### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
$V_{RRM}$	35 V, 45 V, 60 V
$I_{FSM}$	150 A
$V_F$	0.54 V, 0.60 V
$I_R$	100 $\mu$ A
$T_J$ max.	175 °C
Package	D <sup>2</sup> PAK (TO-263AB)
Circuit configuration	Common cathode

### FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

### MECHANICAL DATA

**Case:** D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test

**Polarity:** as marked

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRB25H35CT	MBRB25H45CT	MBRB25H60CT	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	60	V
Working peak reverse voltage	V <sub>RWM</sub>	35	45	60	
Maximum DC blocking voltage	V <sub>DC</sub>	35	45	60	
Max. average forward rectified current (fig. 1) <div>total device per diode</div>	I <sub>F(AV)</sub>	30			A
		15			
Non-repetitive avalanche energy per diode at 25 °C, I <sub>AS</sub> = 4 A, L = 10 mH	E <sub>AS</sub>	80			mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	150			A
Peak repetitive reverse surge current per diode at t <sub>p</sub> = 2.0 μs, 1 kHz	I <sub>RRM</sub>	1.0	1.0	0.5	A
Peak non-repetitive reverse energy (8/20 μs waveform)	E <sub>RSM</sub>	25	25	20	mJ
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 kΩ	V <sub>C</sub>	25			kV
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000			V/μs
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175			°C



<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB25H35CT MBRB25H45CT		MBRB25H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	$V_F^{(1)}$	$I_F = 15\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	0.64	-	0.70	V
			$T_J = 125\text{ }^{\circ}\text{C}$	0.50	0.54	0.56	0.60	
		$I_F = 30\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	0.74	-	0.85	
			$T_J = 125\text{ }^{\circ}\text{C}$	0.63	0.67	0.68	0.72	
Maximum reverse current per diode	$I_R^{(2)}$	Rated $V_R$	$T_J = 25\text{ }^{\circ}\text{C}$	-	100	-	100	$\mu\text{A}$
			$T_J = 125\text{ }^{\circ}\text{C}$	6.0	20	4.0	20	mA

**Notes**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width  $\leq 40\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	MBRB	UNIT
Thermal resistance, junction to case per diode	$R_{\theta JC}$	1.5	$^{\circ}\text{C/W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
D <sup>2</sup> PAK (TO-263AB)	MBRB25H60CTHM3/I	1.35	I	800/reel	Tape and reel



## RATINGS AND CHARACTERISTICS CURVES ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

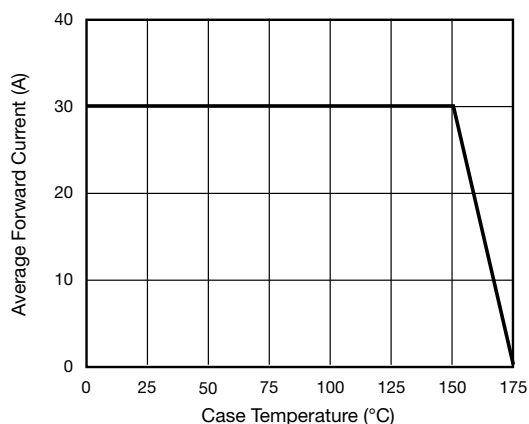


Fig. 1 - Forward Derating Curve (Total)

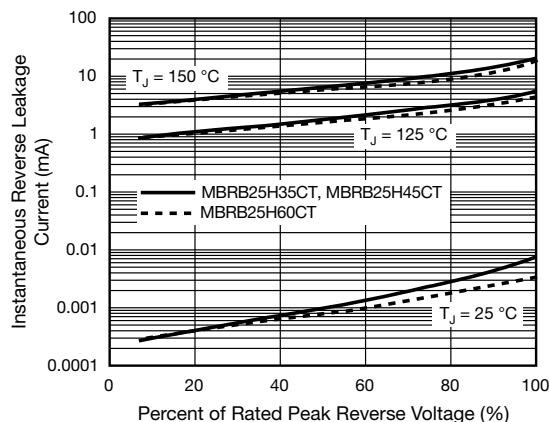


Fig. 4 - Typical Reverse Characteristics Per Diode

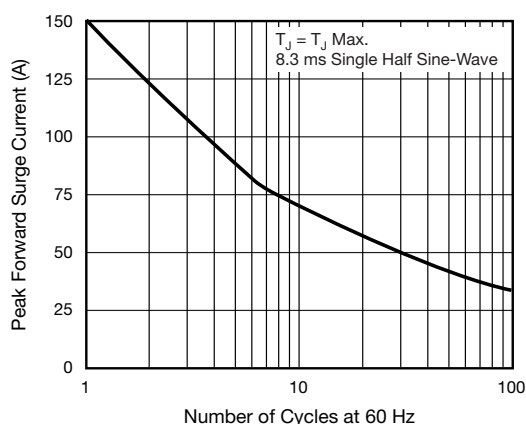


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

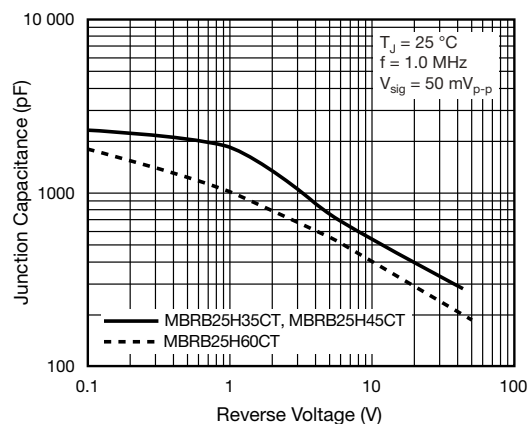


Fig. 5 - Typical Junction Capacitance Per Diode

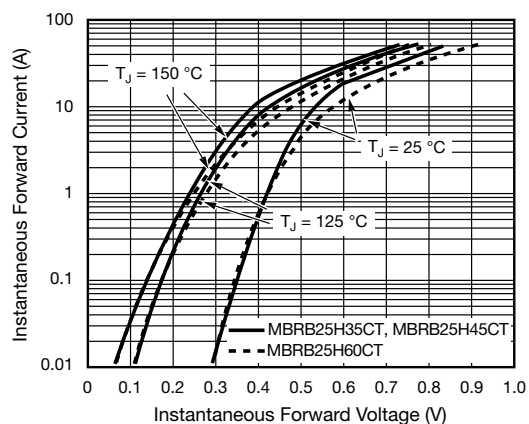


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

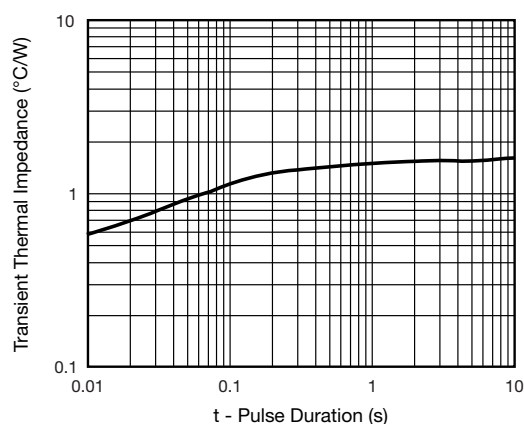
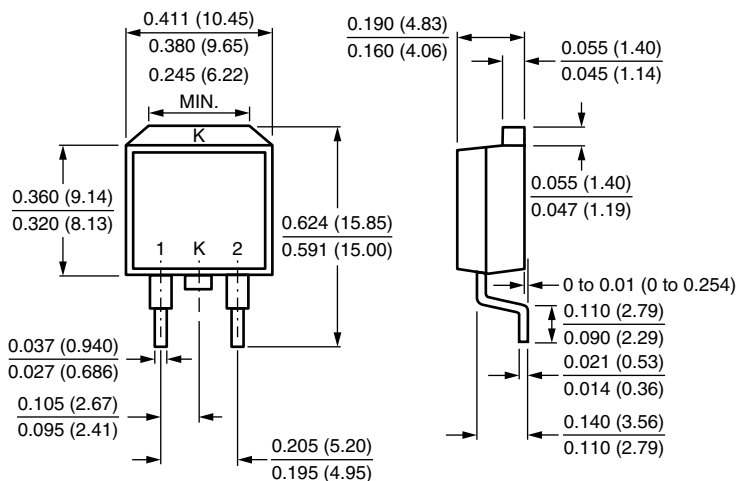


Fig. 6 - Typical Transient Thermal Impedance Per Diode

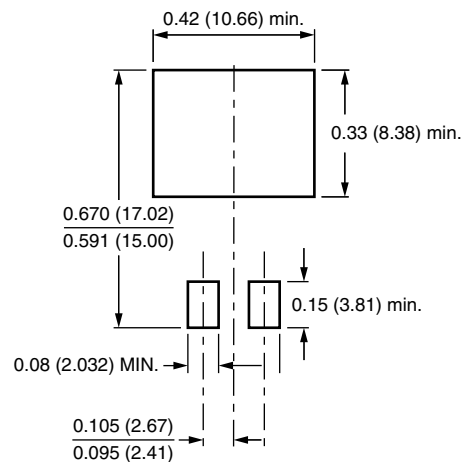


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### D<sup>2</sup>PAK (TO-263AB)



### Mounting Pad Layout





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